

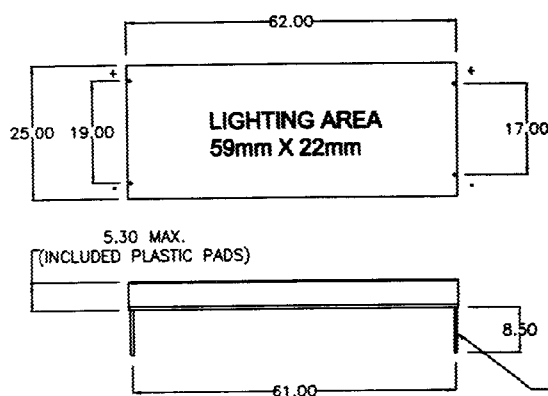
ABSOLUTE MAXIMUM RATINGS

Forward Current	I_F	200mA
Reverse Voltage	V_R	10V
Operating Temperature	T_{opr}	-20 to +70°C
Storage Temperature	T_{stg}	-30 to +80°C

ELECTRO-OPTICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

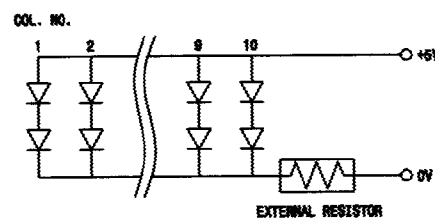
PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	CONDITIONS
Forward Voltage	V_F	3.8	4.1	4.4	V	$I_F=100\text{mA}$
Reverse Current	I_R			100	μA	$V_R=10\text{V}$
Peak Wavelength	λ_p		565		nm	$I_F=100\text{mA}$
Spectral Line Half Width	$\Delta\lambda$		40		nm	$I_F=100\text{mA}$
Brightness	B	60			cd/m^2	$I_F=100\text{mA}$

MECHANICAL OUTLINE



ALL DIMENSION IN MM
NO SCALE
TOL.: $\pm 0.3\text{MM}$

CIRCUIT DIAGRAM



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Rev A